

# 24-Stage Frequency Divider

## MC14521B

The MC14521B consists of a chain of 24 flip-flops with an input circuit that allows three modes of operation. The input will function as a crystal oscillator, an RC oscillator, or as an input buffer for an external oscillator. Each flip-flop divides the frequency of the previous flip-flop by two, consequently this part will count up to  $2^{24} = 16,777,216$ . The count advances on the negative going edge of the clock. The outputs of the last seven-stages are available for added flexibility.

### Features

- All Stages are Resettable
- Reset Disables the RC Oscillator for Low Standby Power Drain
- RC and Crystal Oscillator Outputs Are Capable of Driving External Loads
- Test Mode to Reduce Test Time
- $V_{DD}'$  and  $V_{SS}'$  Pins Brought Out on Crystal Oscillator Inverter to Allow the Connection of External Resistors for Low-Power Operation
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load over the Rated Temperature Range
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

### MAXIMUM RATINGS (Voltages Referenced to $V_{SS}$ )

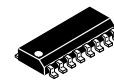
Parameter	Symbol	Value	Unit
DC Supply Voltage Range	$V_{DD}$	-0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	$V_{in}$ , $V_{out}$	-0.5 to $V_{DD}$ +0.5	V
Input or Output Current (DC or Transient) per Pin	$I_{in}$ , $I_{out}$	$\pm 10$	mA
Power Dissipation, per Package (Note 1)	$P_D$	500	mW
Ambient Temperature Range	$T_A$	-55 to +125	$^{\circ}C$
Storage Temperature Range	$T_{stg}$	-65 to +150	$^{\circ}C$
Lead Temperature (8-Second Soldering)	$T_L$	260	$^{\circ}C$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. Operating the device outside its recommended conditions, but still within its maximum rated limits may not cause immediate damage. However, doing so can lead to reduced performance, unpredictable behavior, and potentially shorten the device's lifespan or reliability.

1. Temperature Derating: "D/DW" Package: -7.0 mW/ $^{\circ}C$  From 65  $^{\circ}C$  To 125  $^{\circ}C$

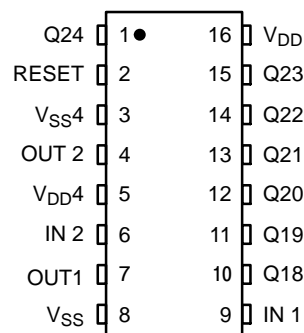
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

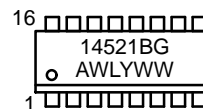


1  
SOIC-16  
D SUFFIX  
CASE 751B

### PIN ASSIGNMENT



### MARKING DIAGRAMS



- A = Assembly Location
- WL, L = Wafer Lot
- YY, Y = Year
- WW, W = Work Week
- G = Pb-Free Package

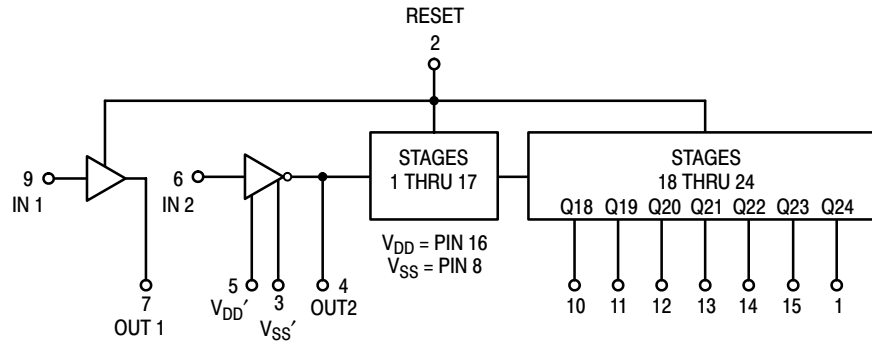
### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

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## BLOCK DIAGRAM



Output	Count Capacity
Q18	$2^{18} = 262,144$
Q19	$2^{19} = 524,288$
Q20	$2^{20} = 1,048,576$
Q21	$2^{21} = 2,097,152$
Q22	$2^{22} = 4,194,304$
Q23	$2^{23} = 8,388,608$
Q24	$2^{24} = 16,777,216$

## ORDERING INFORMATION

Device	Package	Shipping†
MC14521BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14521BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14521BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

## DISCONTINUED (Note 2)

NLV14521BDG*	SOIC-16 (Pb-Free)	48 Units / Rail
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† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

\* NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

2. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on [www.onsemi.com](http://www.onsemi.com).

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## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	-55 °C		25 °C			125 °C		Unit
			Min	Max	Min	Typ (Note 3)	Max	Min	Max	
Output Voltage "0" Level V <sub>in</sub> = V <sub>DD</sub> or 0	V <sub>OL</sub>	5.0	-	0.05	-	0	0.05	-	0.05	Vdc
		10	-	0.05	-	0	0.05	-	0.05	
15		-	0.05	-	0	0.05	-	0.05		
"1" Level V <sub>in</sub> = 0 or V <sub>DD</sub>	V <sub>OH</sub>	5.0	4.95	-	4.95	5.0	-	4.95	-	Vdc
		10	9.95	-	9.95	10	-	9.95	-	
		15	14.95	-	14.95	15	-	14.95	-	
Input Voltage "0" Level (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	V <sub>IL</sub>	5.0	-	1.5	-	2.25	1.5	-	1.5	Vdc
		10	-	3.0	-	4.50	3.0	-	3.0	
15		-	4.0	-	6.75	4.0	-	4.0		
"1" Level (V <sub>O</sub> = 0.5 or 4.5 Vdc) (V <sub>O</sub> = 1.0 or 9.0 Vdc) (V <sub>O</sub> = 1.5 or 13.5 Vdc)	V <sub>IH</sub>	5.0	3.5	-	3.5	2.75	-	3.5	-	Vdc
		10	7.0	-	7.0	5.50	-	7.0	-	
		15	11	-	11	8.25	-	11	-	
Output Drive Current (V <sub>OH</sub> = 4.5 Vdc) (V <sub>OH</sub> = 9.0 Vdc) (V <sub>OH</sub> = 13 Vdc) Source Pin 4  (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc) Source Pins 1, 7, 10, 11, 12, 13, 14 and 15  (V <sub>OL</sub> = 0.4 Vdc) (V <sub>OL</sub> = 0.5 Vdc) (V <sub>OL</sub> = 1.5 Vdc) Sink	I <sub>OH</sub>	5.0	-0.25	-	-0.2	-0.36	-	-0.14	-	mAdc
		10	-0.62	-	-0.5	-0.9	-	-0.35	-	
		15	-1.8	-	-1.5	-3.5	-	-1.1	-	
	I <sub>OL</sub>	5.0	-3.0	-	-2.4	-4.2	-	-1.7	-	mAdc
		5.0	-0.64	-	-0.51	-0.88	-	-0.36	-	
		10	-1.6	-	-1.3	-2.25	-	-0.9	-	
15	-4.2	-	-3.4	-8.8	-	-2.4	-			
I <sub>OL</sub>	5.0	0.64	-	0.51	0.88	-	0.36	-	mAdc	
10	1.6	-	1.3	2.25	-	0.9	-			
15	4.2	-	3.4	8.8	-	2.4	-			
Input Current	I <sub>in</sub>	15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	-	-	-	-	5.0	7.5	-	-	pF
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	-	5.0	-	0.005	5.0	-	150	μAdc
		10	-	10	-	0.010	10	-	300	
		15	-	20	-	0.015	20	-	600	
Total Supply Current (Note 4, 5) (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	I <sub>T</sub>	5.0	I <sub>T</sub> = (0.42 μA/kHz) f + I <sub>DD</sub>							μAdc
		10	I <sub>T</sub> = (0.85 μA/kHz) f + I <sub>DD</sub>							
		15	I <sub>T</sub> = (1.40 μA/kHz) f + I <sub>DD</sub>							

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

4. The formulas given are for the typical characteristics only at 25 °C.

5. To calculate total supply current at loads other than 50 pF: I<sub>T</sub>(C<sub>L</sub>) = I<sub>T</sub>(50 pF) + (C<sub>L</sub> - 50) Vfk where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.003.

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## SWITCHING CHARACTERISTICS (Note 6) ( $C_L = 50 \text{ pF}$ , $T_A = 25 \text{ }^\circ\text{C}$ )

Characteristic	Symbol	V <sub>DD</sub> Vdc	Min	Typ (Note 7)	Max	Unit
Output Rise and Fall Time (Counter Outputs) $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 12.5 \text{ ns}$	$t_{TLH}, t_{THL}$	5.0 10 15	– – –	100 50 40	200 100 80	ns
Propagation Delay Time Clock to Q18 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 4415 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 1667 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1275 \text{ ns}$ Clock to Q24 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 5915 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 2167 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1675 \text{ ns}$	$t_{PHL}, t_{PLH}$	5.0 10 15  5.0 10 15	– – –  – – –	4.5 1.7 1.3  6.0 2.2 1.7	9.0 3.5 2.7  12 4.5 3.5	$\mu\text{s}$
Propagation Delay Time Reset to Q <sub>n</sub> $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 1215 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 467 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 350 \text{ ns}$	$t_{PHL}$	5.0 10 15	– – –	1300 500 375	2600 1000 750	ns
Clock Pulse Width	$t_{WH(cl)}$	5.0 10 15	385 150 120	140 55 40	– – –	ns
Clock Pulse Frequency	$f_{cl}$	5.0 10 15	– – –	3.5 9.0 12	2.0 5.0 6.5	MHz
Clock Rise and Fall Time	$t_{TLH}, t_{THL}$	5.0 10 15	– – –	– – –	15 5.0 4.0	$\mu\text{s}$
Reset Pulse Width	$t_{WH(R)}$	5.0 10 15	1400 600 450	700 300 225	– – –	ns
Reset Removal Time	$t_{rem}$	5.0 10 15	30 0 –40	–200 –160 –110	– – –	ns

6. The formulas given are for the typical characteristics only at 25 °C.

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

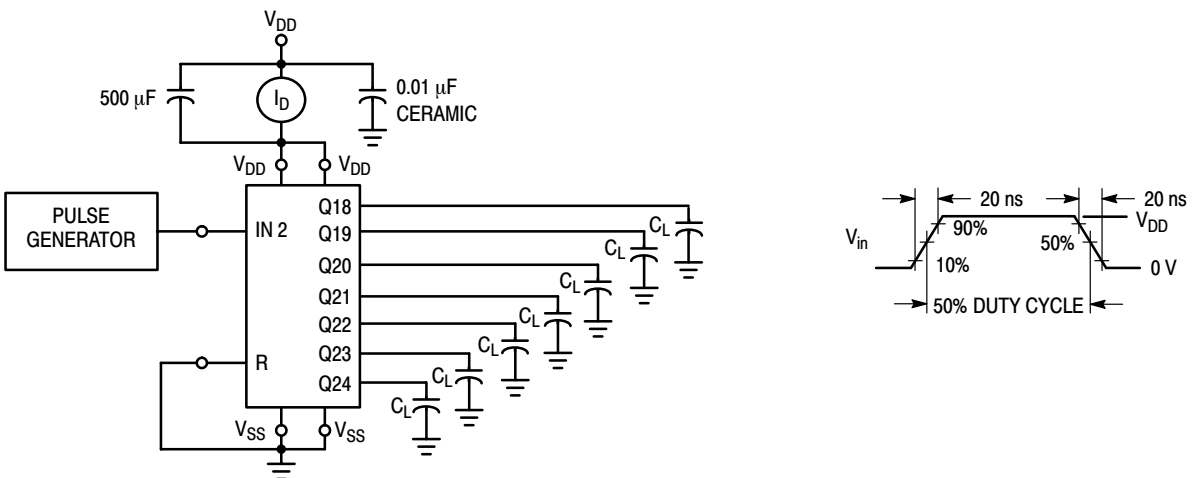


Figure 1. Power Dissipation Test Circuit and Waveform

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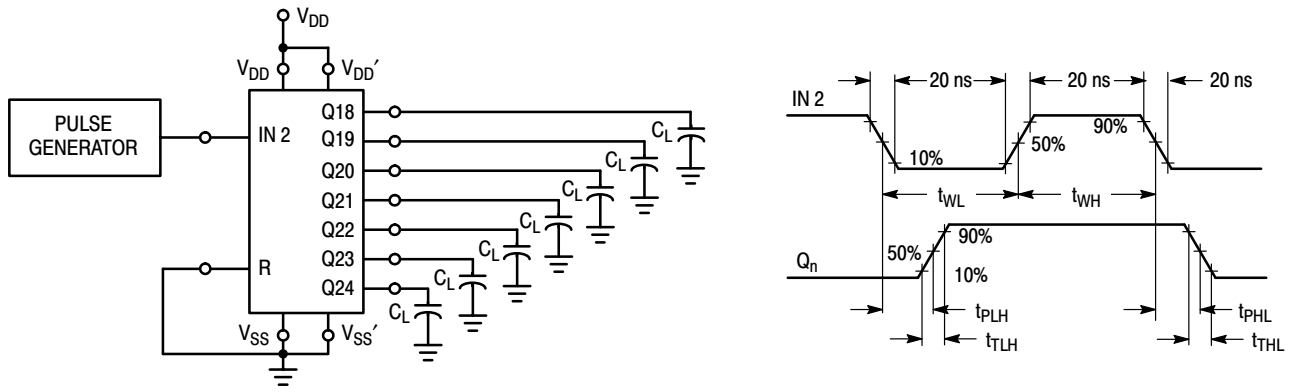
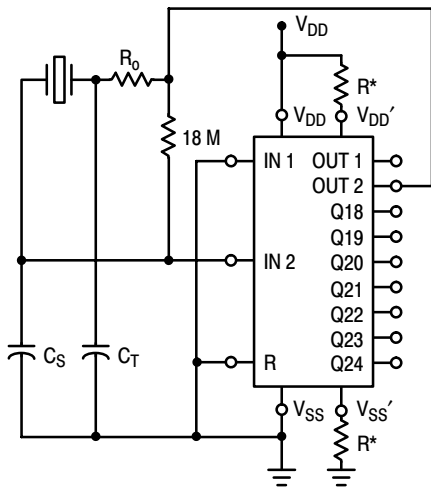


Figure 2. Switching Time Test Circuit and Waveforms



\* Optional for low power operation,  $10 \text{ k}\Omega \leq R \leq 70 \text{ k}\Omega$ .

Figure 3. Crystal Oscillator Circuit

Characteristic	500 kHz Circuit	50 kHz Circuit	Unit
Crystal Characteristics			
Resonant Frequency	500	50	kHz
Equivalent Resistance, $R_S$	1.0	6.2	$\text{k}\Omega$
External Resistor/Capacitor Values			
$R_o$	47	750	$\text{k}\Omega$
$C_T$	82	82	pF
$C_S$	20	20	pF
Frequency Stability			
Frequency Change as a Function of $V_{DD}$ ( $T_A = 25^\circ\text{C}$ )			
$V_{DD}$ Change from 5.0 V to 10 V	+ 6.0	+ 2.0	ppm
$V_{DD}$ Change from 10 V to 15 V	+ 2.0	+ 2.0	ppm
Frequency Change as a Function of Temperature ( $V_{DD} = 10 \text{ V}$ )			
$T_A$ Change from $-55^\circ\text{C}$ to $+25^\circ\text{C}$	- 4.0	- 2.0	ppm
MC14521 only	+ 100	+ 120	ppm
Complete Oscillator*			
$T_A$ Change from $+25^\circ\text{C}$ to $+125^\circ\text{C}$	- 2.0	- 2.0	ppm
MC14521 only	- 160	- 560	ppm
Complete Oscillator*			

\*Complete oscillator includes crystal, capacitors, and resistors.

Figure 4. Typical Data for Crystal Oscillator Circuit

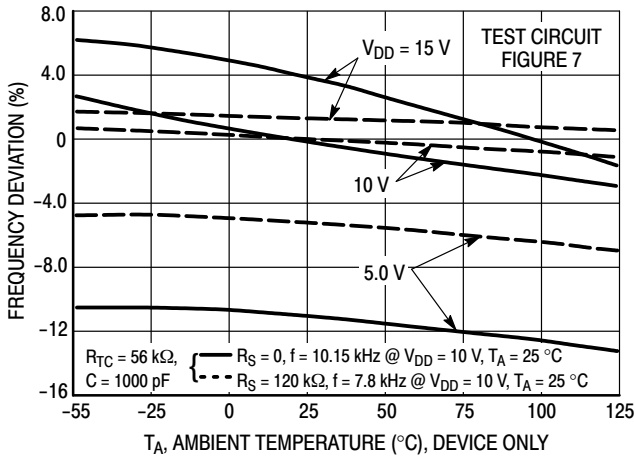


Figure 5. RC Oscillator Stability

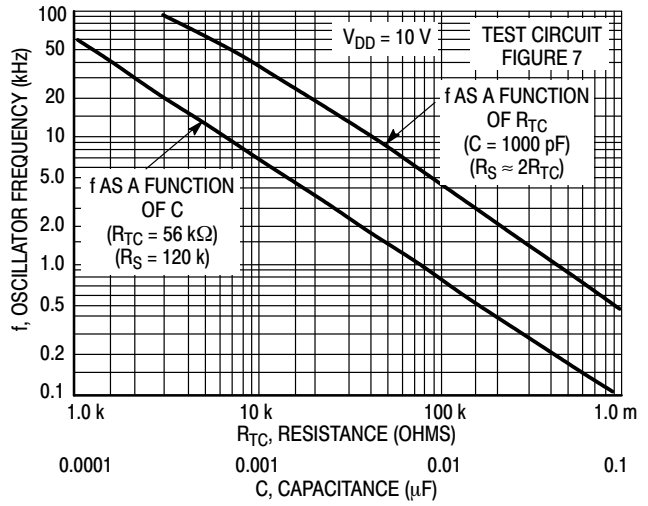


Figure 6. RC Oscillator Frequency as a Function of  $R_{TC}$  and  $C$

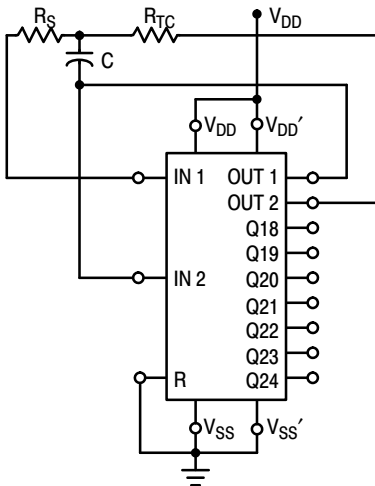


Figure 7. RC Oscillator Circuit

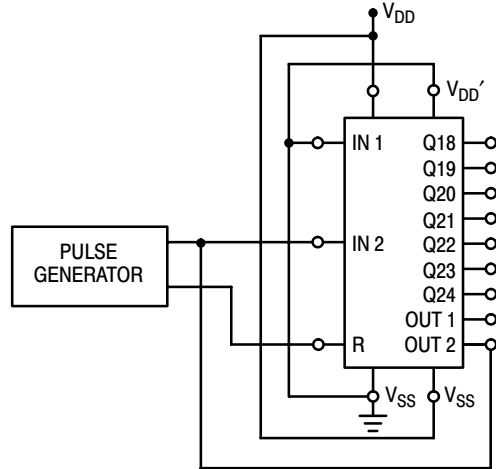


Figure 8. Functional Test Circuit

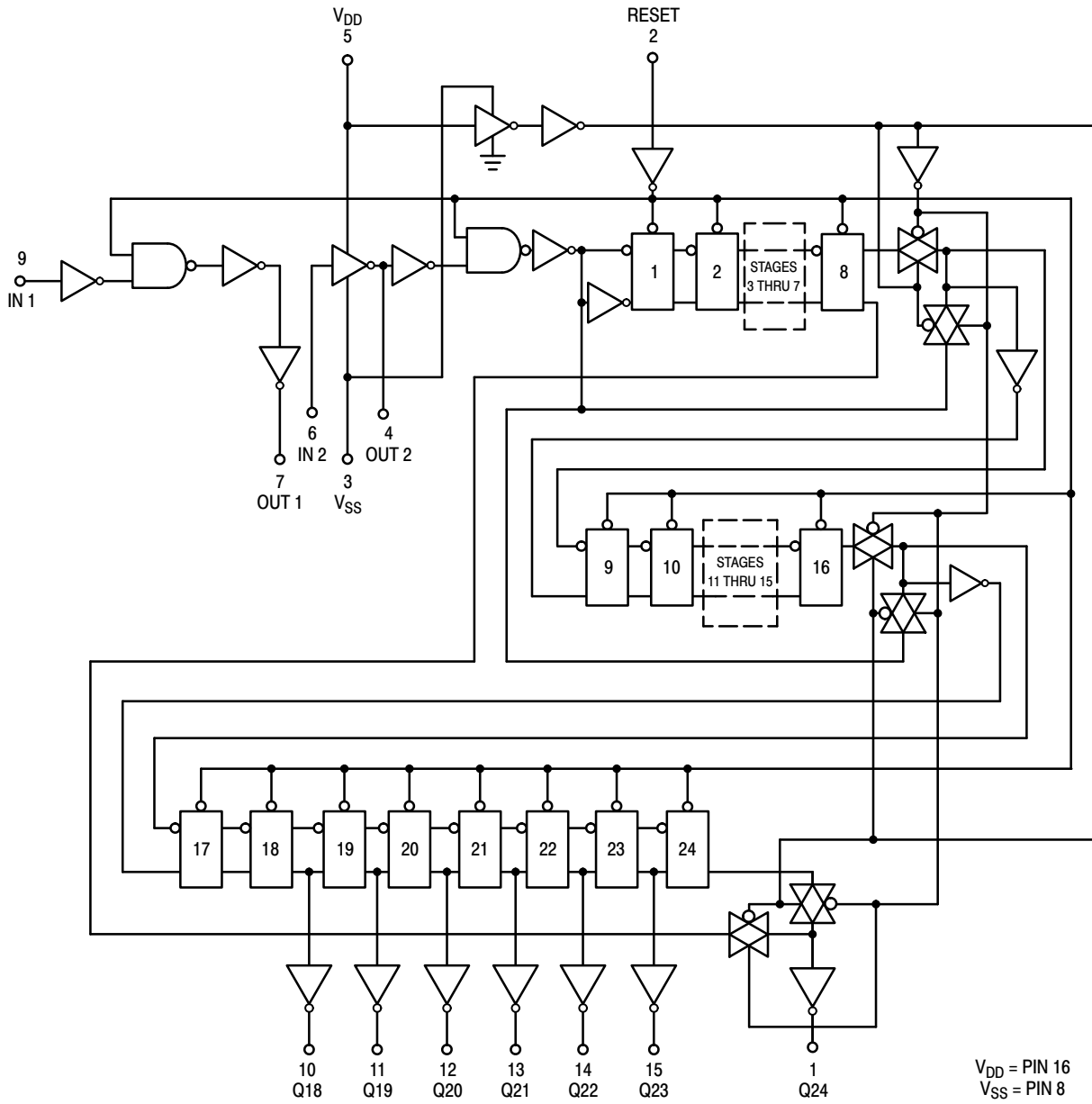
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## FUNCTIONAL TEST SEQUENCE

	Inputs		Outputs				Comments
	Reset	In 2	Out 2	V <sub>SS'</sub>	V <sub>DD'</sub>	Q18 thru Q24	
<p>A test function (see Figure 8) has been included for the reduction of test time required to exercise all 24 counter stages. This test function divides the counter into three 8-stage sections, and 255 counts are loaded in each of the 8-stage sections in parallel. All flip-flops are now at a logic "1". The counter is now returned to the normal 24-stages in series configuration. One more pulse is entered into Input 2 (In 2) which will cause the counter to ripple from an all "1" state to an all "0" state.</p>	1	0	0	V <sub>DD</sub>	GND	0	Counter is in three 8-stage sections in parallel mode Counter is reset. In 2 and Out 2 are connected together.
	0	1	1	↓	↓	0	First "0" to "1" transition on In 2, Out 2 node.
		0	0				255 "0" to "1" transitions are clocked into this In 2, Out 2 node.
		1	1			1	The 255th "0" to "1" transition.
		0	0			1	
		0	0	GND	↓	1	Counter converted back to 24-stages in series mode.
		1	0		V <sub>DD</sub>	1	Out 2 converts back to an output.
		1	0			1	
		0	1			0	Counter ripples from an all "1" state to an all "0" stage.

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## LOGIC DIAGRAM

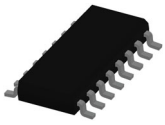


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## REVISION HISTORY

Revision	Description of Changes	Date
11	Rebranded the Data Sheet to <b>onsemi</b> format. NLV14521BDG OPN marked as Discontinued.	10/3/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

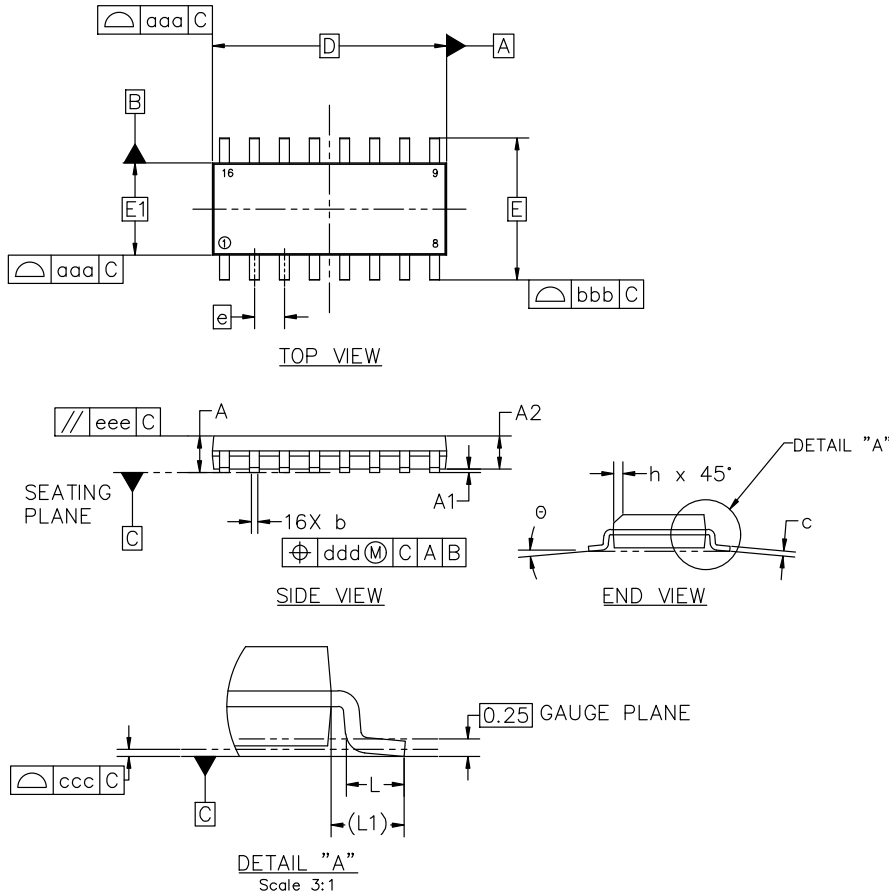


**SOIC-16 9.90x3.90x1.37 1.27P**  
**CASE 751B**  
**ISSUE M**

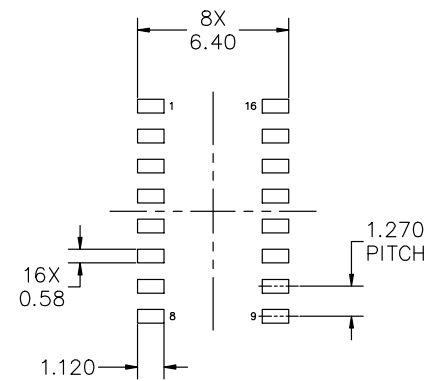
DATE 18 OCT 2024

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.18	0.25
A2	1.25	1.37	1.50
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	---	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
θ	0°	---	7°
TOLERANCE OF FORM AND POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.25		
eee	0.10		



RECOMMENDED MOUNTING FOOTPRINT

\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE onsemi SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D

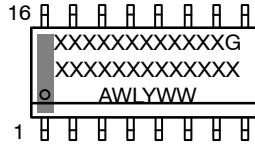
<b>DOCUMENT NUMBER:</b>	<b>98ASB42566B</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>SOIC-16 9.90X3.90X1.37 1.27P</b>	<b>PAGE 1 OF 2</b>

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**SOIC-16 9.90x3.90x1.37 1.27P**  
**CASE 751B**  
**ISSUE M**

DATE 18 OCT 2024

**GENERIC  
MARKING DIAGRAM\***



XXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

<p><b>STYLE 1:</b></p> <p>PIN 1. COLLECTOR  2. BASE  3. EMITTER  4. NO CONNECTION  5. EMITTER  6. BASE  7. COLLECTOR  8. COLLECTOR  9. BASE  10. EMITTER  11. NO CONNECTION  12. EMITTER  13. BASE  14. COLLECTOR  15. EMITTER  16. COLLECTOR</p>	<p><b>STYLE 2:</b></p> <p>PIN 1. CATHODE  2. ANODE  3. NO CONNECTION  4. CATHODE  5. CATHODE  6. NO CONNECTION  7. ANODE  8. CATHODE  9. CATHODE  10. ANODE  11. NO CONNECTION  12. CATHODE  13. CATHODE  14. NO CONNECTION  15. ANODE  16. CATHODE</p>	<p><b>STYLE 3:</b></p> <p>PIN 1. COLLECTOR, DYE #1  2. BASE, #1  3. EMITTER, #1  4. COLLECTOR, #1  5. COLLECTOR, #2  6. BASE, #2  7. EMITTER, #2  8. COLLECTOR, #2  9. COLLECTOR, #3  10. BASE, #3  11. EMITTER, #3  12. COLLECTOR, #3  13. COLLECTOR, #4  14. BASE, #4  15. EMITTER, #4  16. COLLECTOR, #4</p>	<p><b>STYLE 4:</b></p> <p>PIN 1. COLLECTOR, DYE #1  2. COLLECTOR, #1  3. COLLECTOR, #2  4. COLLECTOR, #2  5. COLLECTOR, #3  6. COLLECTOR, #3  7. COLLECTOR, #4  8. COLLECTOR, #4  9. BASE, #4  10. EMITTER, #4  11. BASE, #3  12. EMITTER, #3  13. BASE, #2  14. EMITTER, #2  15. BASE, #1  16. EMITTER, #1</p>
<p><b>STYLE 5:</b></p> <p>PIN 1. DRAIN, DYE #1  2. DRAIN, #1  3. DRAIN, #2  4. DRAIN, #2  5. DRAIN, #3  6. DRAIN, #3  7. DRAIN, #4  8. DRAIN, #4  9. GATE, #4  10. SOURCE, #4  11. GATE, #3  12. SOURCE, #3  13. GATE, #2  14. SOURCE, #2  15. GATE, #1  16. SOURCE, #1</p>	<p><b>STYLE 6:</b></p> <p>PIN 1. CATHODE  2. CATHODE  3. CATHODE  4. CATHODE  5. CATHODE  6. CATHODE  7. CATHODE  8. CATHODE  9. ANODE  10. ANODE  11. ANODE  12. ANODE  13. ANODE  14. ANODE  15. ANODE  16. ANODE</p>	<p><b>STYLE 7:</b></p> <p>PIN 1. SOURCE N-CH  2. COMMON DRAIN (OUTPUT)  3. COMMON DRAIN (OUTPUT)  4. GATE P-CH  5. COMMON DRAIN (OUTPUT)  6. COMMON DRAIN (OUTPUT)  7. COMMON DRAIN (OUTPUT)  8. SOURCE P-CH  9. SOURCE P-CH  10. COMMON DRAIN (OUTPUT)  11. COMMON DRAIN (OUTPUT)  12. COMMON DRAIN (OUTPUT)  13. GATE N-CH  14. COMMON DRAIN (OUTPUT)  15. COMMON DRAIN (OUTPUT)  16. SOURCE N-CH</p>	

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<b>DESCRIPTION:</b>	<b>SOIC-16 9.90X3.90X1.37 1.27P</b>	<b>PAGE 2 OF 2</b>

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